

MOS FIELD EFFECT TRANSISTOR $\mu PA1812$

P-CHANNEL MOS FIELD EFFECT TRANSISTOR FOR SWITCHING

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DESCRIPTION

The μ PA1812 is a switching device which can be driven directly by a 4.0-V power source.

The μ PA1812 features a low on-state resistance and excellent switching characteristics, and is suitable for applications such as power switch of portable machine and so on.

FEATURES

- Can be driven by a 4.0-V power source
- Low on-state resistance $R_{DS(on)1} = 39 \text{ m}\Omega \text{ MAX.}$ (Vgs = -10 V, Ip = -2.5 A) $R_{DS(on)2} = 63 \text{ m}\Omega \text{ MAX.}$ (Vgs = -4.5 V, Ip = -2.5 A) $R_{DS(on)3} = 69 \text{ m}\Omega \text{ MAX.}$ (Vgs = -4.0 V, Ip = -2.5 A)

ORDERING INFORMATION

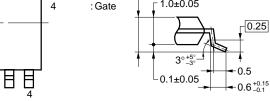
PART NUMBER	PACKAGE
μPA1812GR-9JG	Power TSSOP8

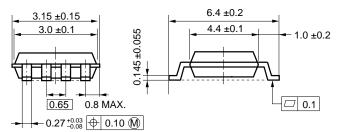
ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Drain to Source Voltage	VDSS	-30	V
Gate to Source Voltage	Vgss	-20/+5	V
Drain Current (DC)	ID(DC)	±5.0	А
Drain Current (pulse) Note1	D(pulse)	±20	А
Total Power Dissipation Note2	Pτ	2.0	W
Channel Temperature	Tch	150	°C
Storage Temperature	Tstg	–55 to +150	°C

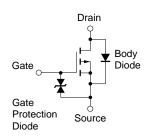


PACKAGE DRAWING (Unit : mm)





EQUIVALENT CIRCUIT



Notes 1. PW \leq 10 μ s, Duty Cycle \leq 1%

- 2. Mounted on ceramic substrate of 5000 mm² x 1.1 mm
- **Remark** The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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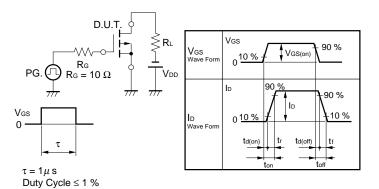
Document No. Date Published Printed in Japan

D12967EJ2V0DS00 (2nd edition) May 2001 NS CP(K) The mark **★** shows major revised points.

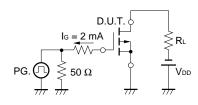
ELECTRICAL CHARACTERISTICS (TA = 25°C)

CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	IDSS	$V_{DS} = -30 V, V_{GS} = 0 V$			-10	μA
Gate Leakage Current	lgss	$V_{GS} = \pm 20 \text{ V}, \text{ V}_{DS} = 0 \text{ V}$			±10	μA
Gate Cut-off Voltage	V _{GS(off)}	$V_{DS} = -10 V$, $I_D = -1 mA$	-1.0	-1.6	-2.5	V
Forward Transfer Admittance	y _{fs}	$V_{DS} = -10 V$, $I_D = -2.5 A$	1	8		S
Drain to Source On-state Resistance	RDS(on)1	$V_{GS} = -10 V$, $I_D = -2.5 A$		29	39	mΩ
	RDS(on)2	$V_{GS} = -4.5 \text{ V}, \text{ Id} = -2.5 \text{ A}$		46	63	mΩ
	RDS(on)3	$V_{GS} = -4.0 \text{ V}, \text{ Id} = -2.5 \text{ A}$		52	69	mΩ
Input Capacitance	Ciss	V _{DS} = -10 V		1500		pF
Output Capacitance	Coss	Vgs = 0 V		550		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		270		pF
Turn-on Delay Time	td(on)	$V_{DD} = -10 V$		30		ns
Rise Time	tr	I⊳ = −2.5 A		160		ns
Turn-off Delay Time	td(off)	$V_{GS(on)} = -10 V$		110		ns
Fall Time	tr	$R_G = 10 \Omega$		80		ns
Total Gate Charge	QG	V _{DS} = -24 V		31		nC
Gate to Source Charge	Q _{GS}	I⊳ = −5.0 A		4		nC
Gate to Drain Charge	Qgd	V _{GS} = -10 V		8		nC
Diode Forward Voltage	VF(S-D)	IF = 5.0 A, VGs = 0 V		0.76		V

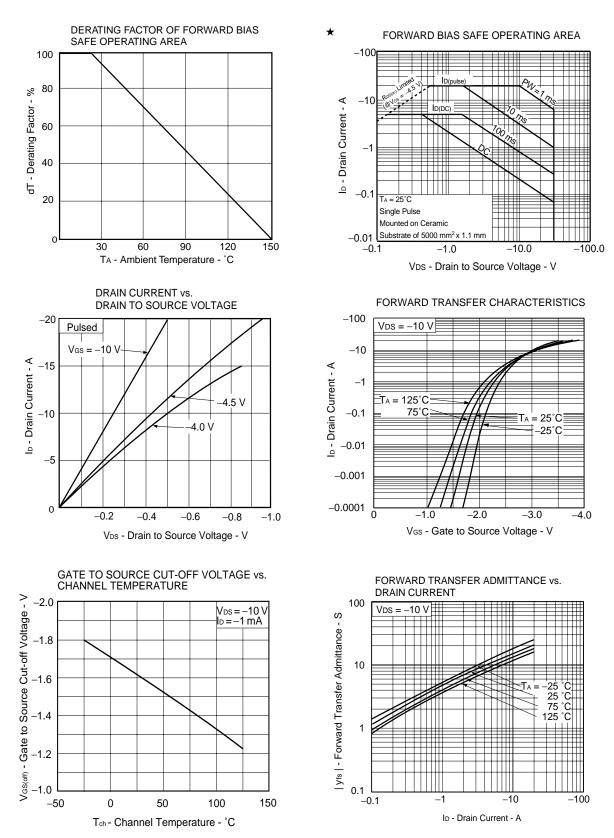
TEST CIRCUIT 1 SWITCHING TIME

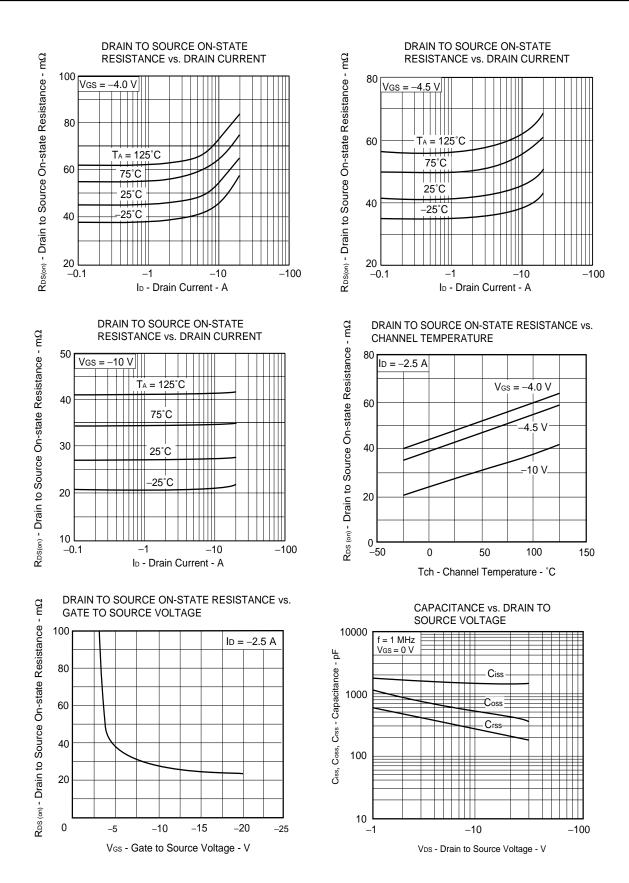


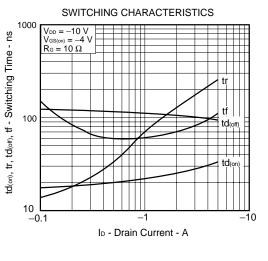
TEST CIRCUIT 2 GATE CHARGE

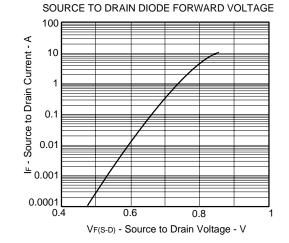


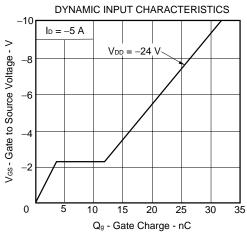


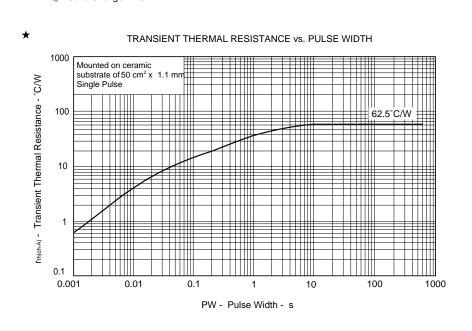












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